

MOSFETs Silicon N-channel MOS (U-MOSIX-H)

# TPH1R104PB

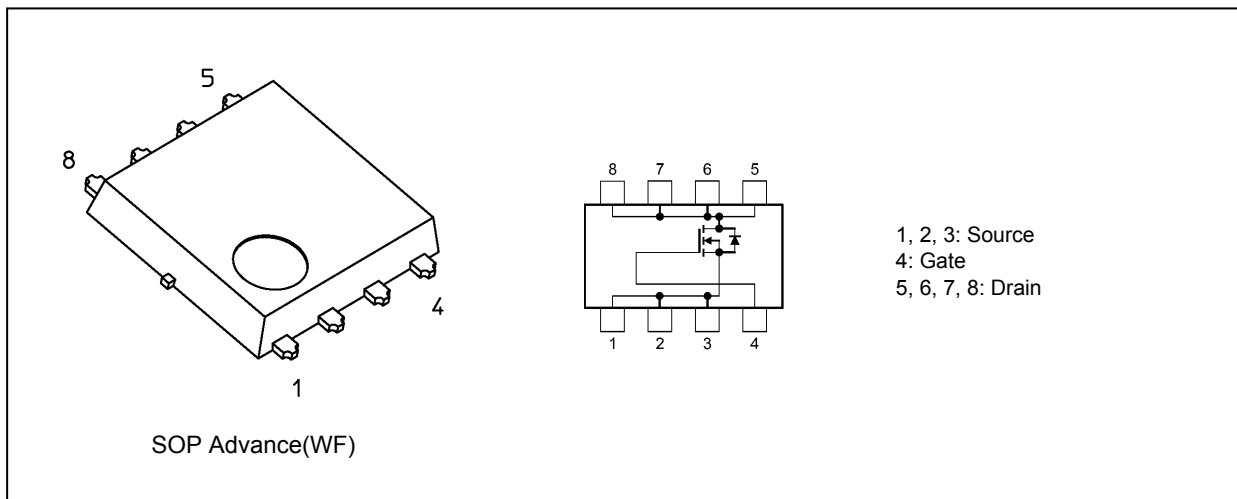
## 1. Applications

- Automotive
- Motor Drivers
- Switching Voltage Regulators

## 2. Features

- (1) AEC-Q101 qualified
- (2) Small, thin package
- (3) Low drain-source on-resistance:  $R_{DS(ON)} = 0.95 \text{ m}\Omega$  (typ.) ( $V_{GS} = 10 \text{ V}$ )
- (4) Low leakage current:  $I_{DSS} = 10 \text{ }\mu\text{A}$  (max) ( $V_{DS} = 40 \text{ V}$ )
- (5) Enhancement mode:  $V_{th} = 2.0$  to  $3.0 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 0.5 \text{ mA}$ )

## 3. Packaging and Internal Circuit



Start of commercial production

2018-03

### 4. Absolute Maximum Ratings (Note) ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	40	V
Gate-source voltage	$V_{GSS}$	$\pm 20$	
Drain current (DC) (Note 1)	$I_D$	120	A
Drain current (pulsed) (Note 1)	$I_{DP}$	360	
Power dissipation ( $T_c = 25\text{ }^\circ\text{C}$ )	$P_D$	132	W
Power dissipation ( $t = 10\text{ s}$ ) (Note 2)		3.0	
Power dissipation ( $t = 10\text{ s}$ ) (Note 3)		0.96	
Single-pulse avalanche energy (Note 4)	$E_{AS}$	140	mJ
Single-pulse avalanche current	$I_{AS}$	120	A
Channel temperature (Note 5)	$T_{ch}$	175	$^\circ\text{C}$
Storage temperature (Note 5)	$T_{stg}$	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal impedance ( $T_c = 25\text{ }^\circ\text{C}$ )	$Z_{th(ch-c)}$	1.13	$^\circ\text{C/W}$
Channel-to-ambient thermal impedance ( $t = 10\text{ s}$ ) (Note 2)	$Z_{th(ch-a)}$	50	
Channel-to-ambient thermal impedance ( $t = 10\text{ s}$ ) (Note 3)	$Z_{th(ch-a)}$	156	

Note 1: Ensure that the channel temperature does not exceed  $175\text{ }^\circ\text{C}$ .

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4:  $V_{DD} = 32\text{ V}$ ,  $T_{ch} = 25\text{ }^\circ\text{C}$  (initial),  $L = 7.47\text{ }\mu\text{H}$ ,  $R_G = 25\text{ }\Omega$ ,  $I_{AS} = 120\text{ A}$

Note 5: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.

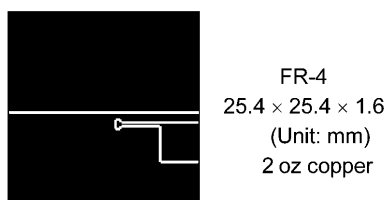


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

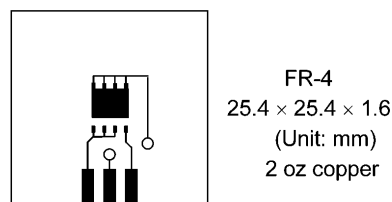


Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

### 6. Electrical Characteristics

#### 6.1. Static Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 1$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = 40\text{ V}, V_{GS} = 0\text{ V}$	—	—	10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	40	—	—	V
	$V_{(BR)DSX}$	$I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$	20	—	—	
Gate threshold voltage	$V_{th}$	$V_{DS} = 10\text{ V}, I_D = 0.5\text{ mA}$	2.0	—	3.0	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = 6\text{ V}, I_D = 60\text{ A}$	—	1.30	1.96	$\text{m}\Omega$
		$V_{GS} = 10\text{ V}, I_D = 60\text{ A}$	—	0.95	1.14	

#### 6.2. Dynamic Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 300\text{ kHz}$	—	4560	—	$\mu\text{F}$
Reverse transfer capacitance	$C_{rss}$		—	320	—	
Output capacitance	$C_{oss}$		—	2940	—	
Gate resistance	$r_g$		—	2.9	—	$\Omega$
Switching time (rise time)	$t_r$	See Fig. 6.2.1	—	8	—	ns
Switching time (turn-on time)	$t_{on}$		—	22	—	
Switching time (fall time)	$t_f$		—	23	—	
Switching time (turn-off time)	$t_{off}$		—	71	—	

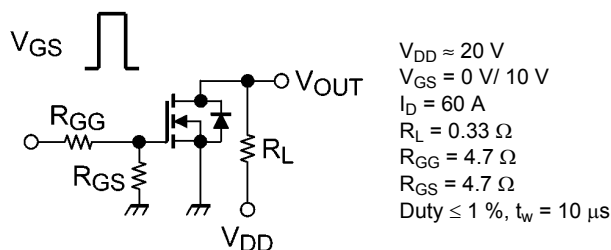


Fig. 6.2.1 Switching Time Test Circuit

#### 6.3. Gate Charge Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx 32\text{ V}, V_{GS} = 10\text{ V}, I_D = 120\text{ A}$	—	55	—	nC
Gate-source charge 1	$Q_{gs1}$		—	20	—	
Gate-drain charge	$Q_{gd}$		—	13	—	

#### 6.4. Source-Drain Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (pulsed) (Note 6)	$I_{DRP}$	—	—	—	360	A
Diode forward voltage	$V_{DSF}$	$I_{DR} = 120\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.2	V

Note 6: Ensure that the channel temperature does not exceed  $175\text{ }^\circ\text{C}$ .

## 7. Marking

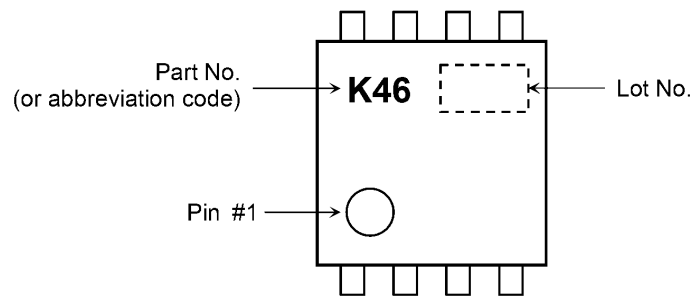


Fig. 7.1 Marking

## 8. Characteristics Curves (Note)

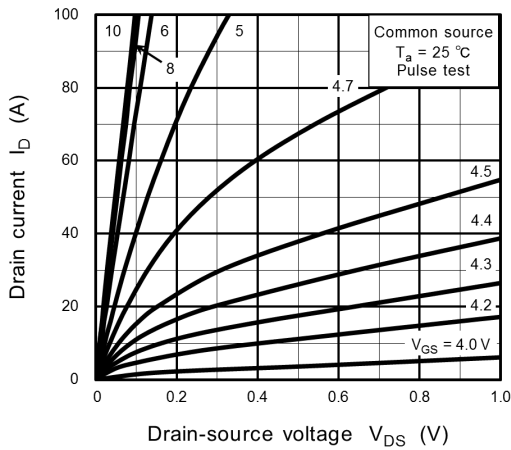


Fig. 8.1  $I_D - V_{DS}$

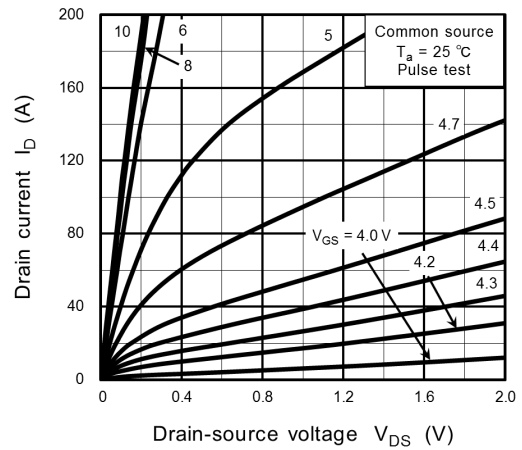


Fig. 8.2  $I_D - V_{DS}$

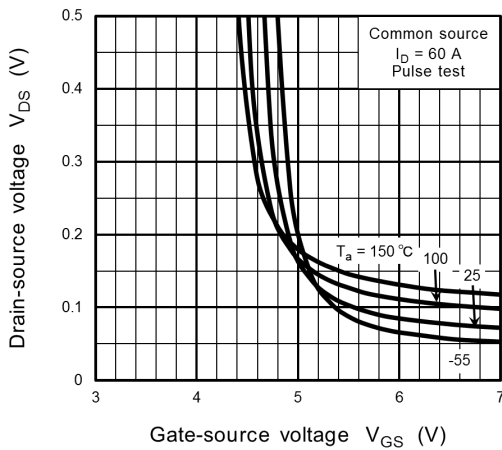


Fig. 8.3  $V_{DS} - V_{GS}$

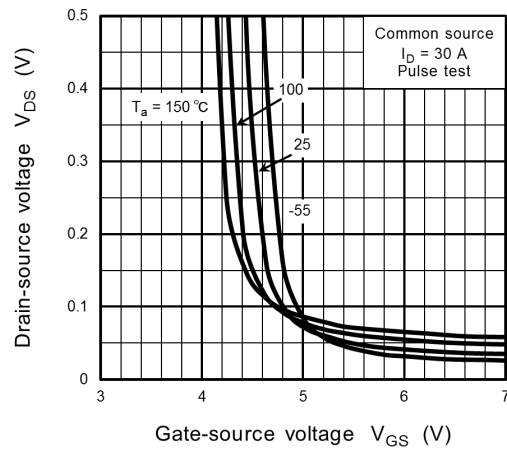


Fig. 8.4  $V_{DS} - V_{GS}$

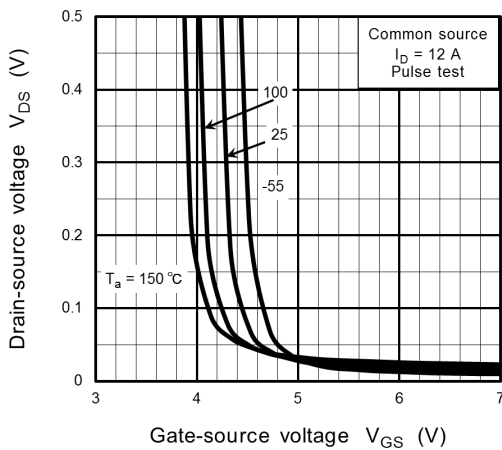


Fig. 8.5  $V_{DS} - V_{GS}$

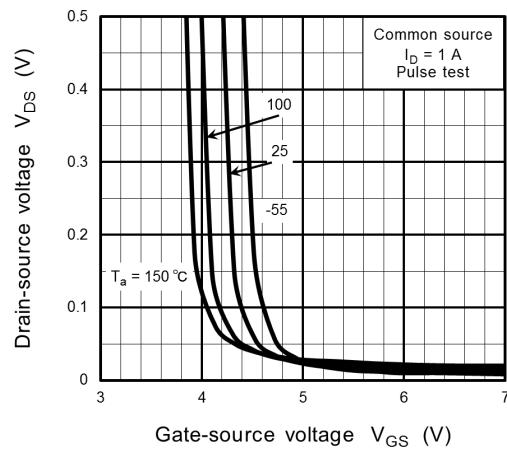
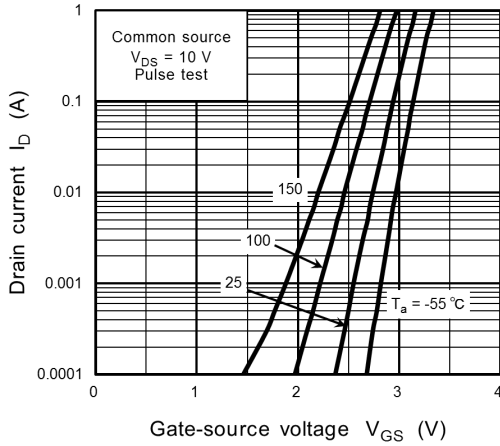
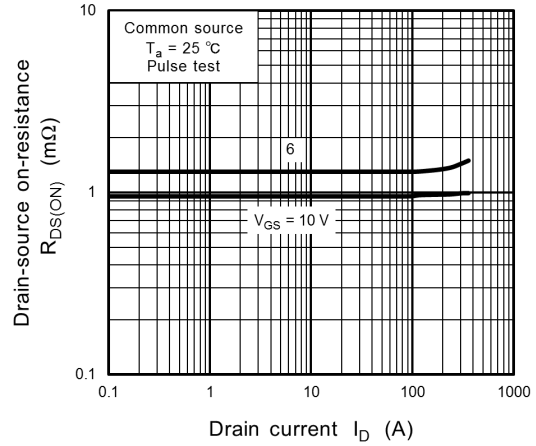


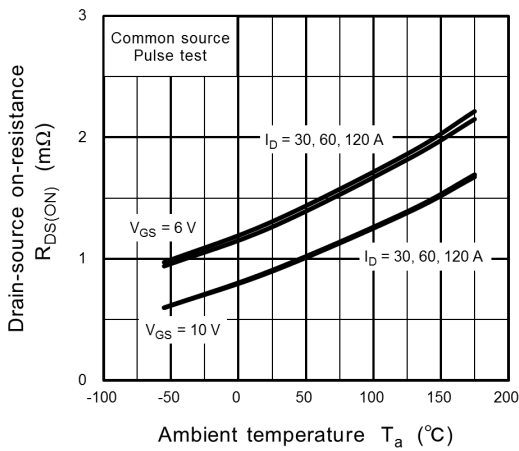
Fig. 8.6  $V_{DS} - V_{GS}$



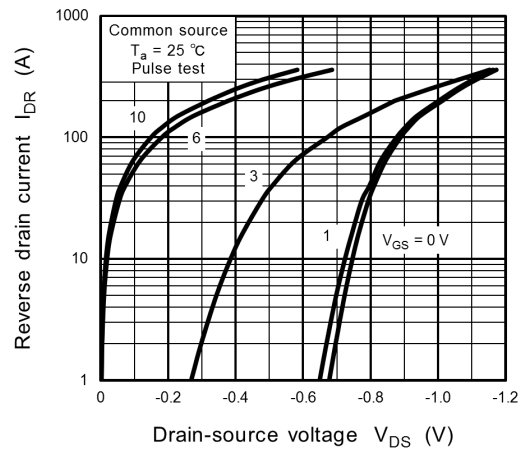
**Fig. 8.7  $I_D - V_{GS}$**



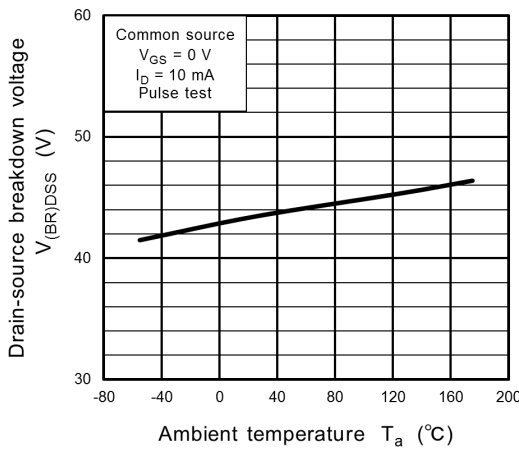
**Fig. 8.8  $R_{DS(ON)} - I_D$**



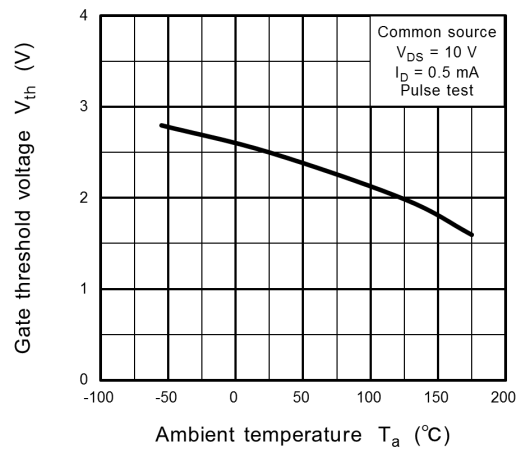
**Fig. 8.9  $R_{DS(ON)} - T_a$**



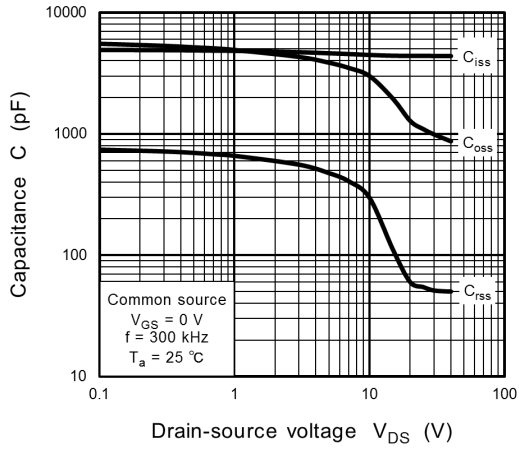
**Fig. 8.10  $I_{DR} - V_{DS}$**



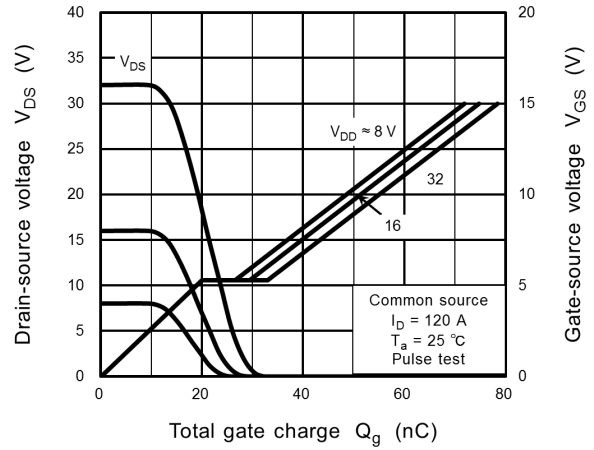
**Fig. 8.11  $V_{(BR)DSS} - T_a$**



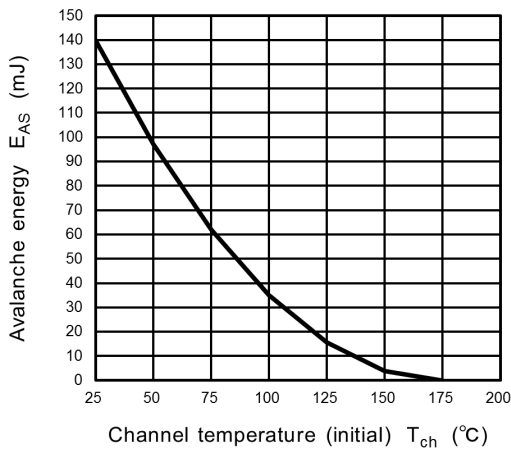
**Fig. 8.12  $V_{th} - T_a$**



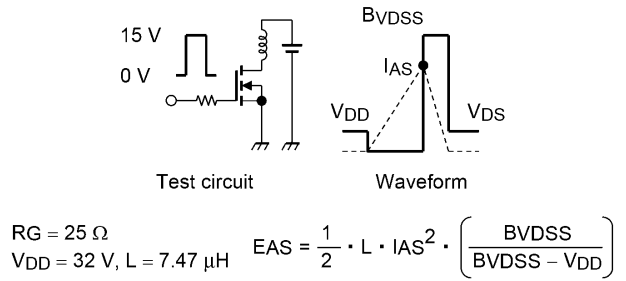
**Fig. 8.13 Capacitance -  $V_{DS}$**



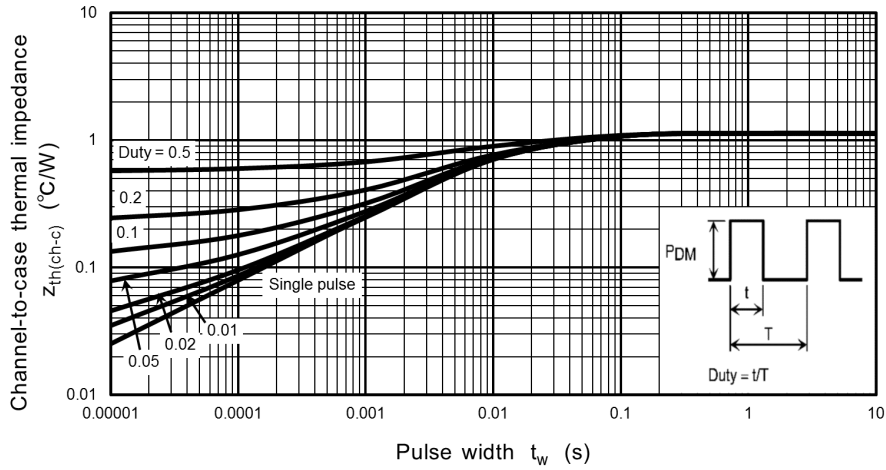
**Fig. 8.14 Dynamic Input/Output Characteristics**



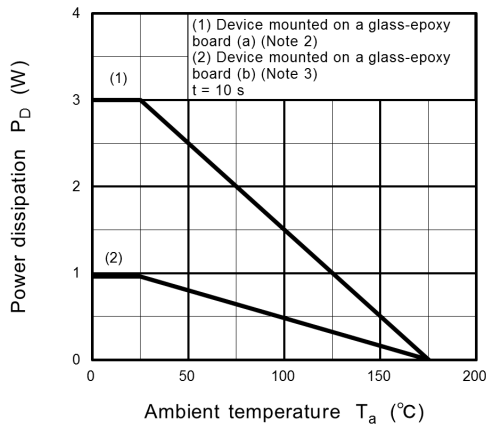
**Fig. 8.15  $E_{AS}$  -  $T_{ch}$ (Guaranteed Maximum)**



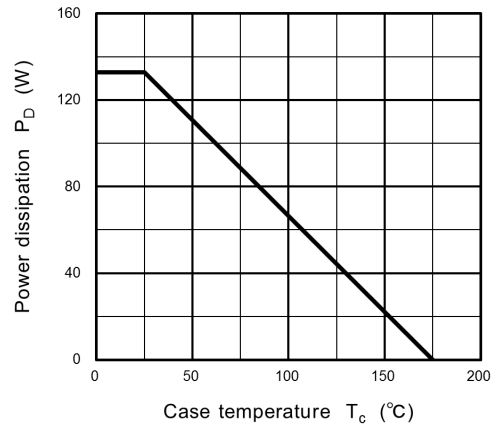
**Fig. 8.16 Test Circuit/Waveform**



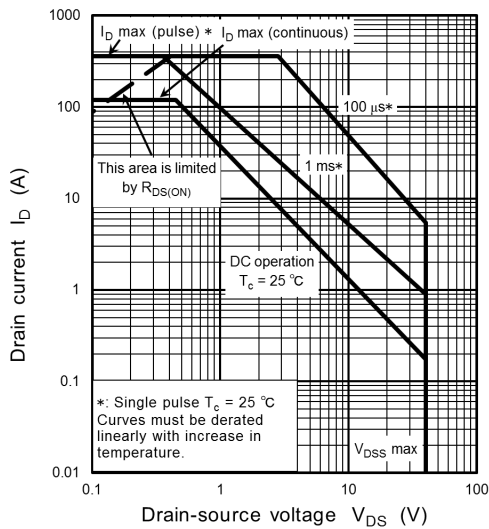
**Fig. 8.17  $Z_{th(ch-c)} - t_w$**   
(Guaranteed Maximum)



**Fig. 8.18  $P_D - T_a$**   
(Guaranteed Maximum)



**Fig. 8.19  $P_D - T_c$**   
(Guaranteed Maximum)



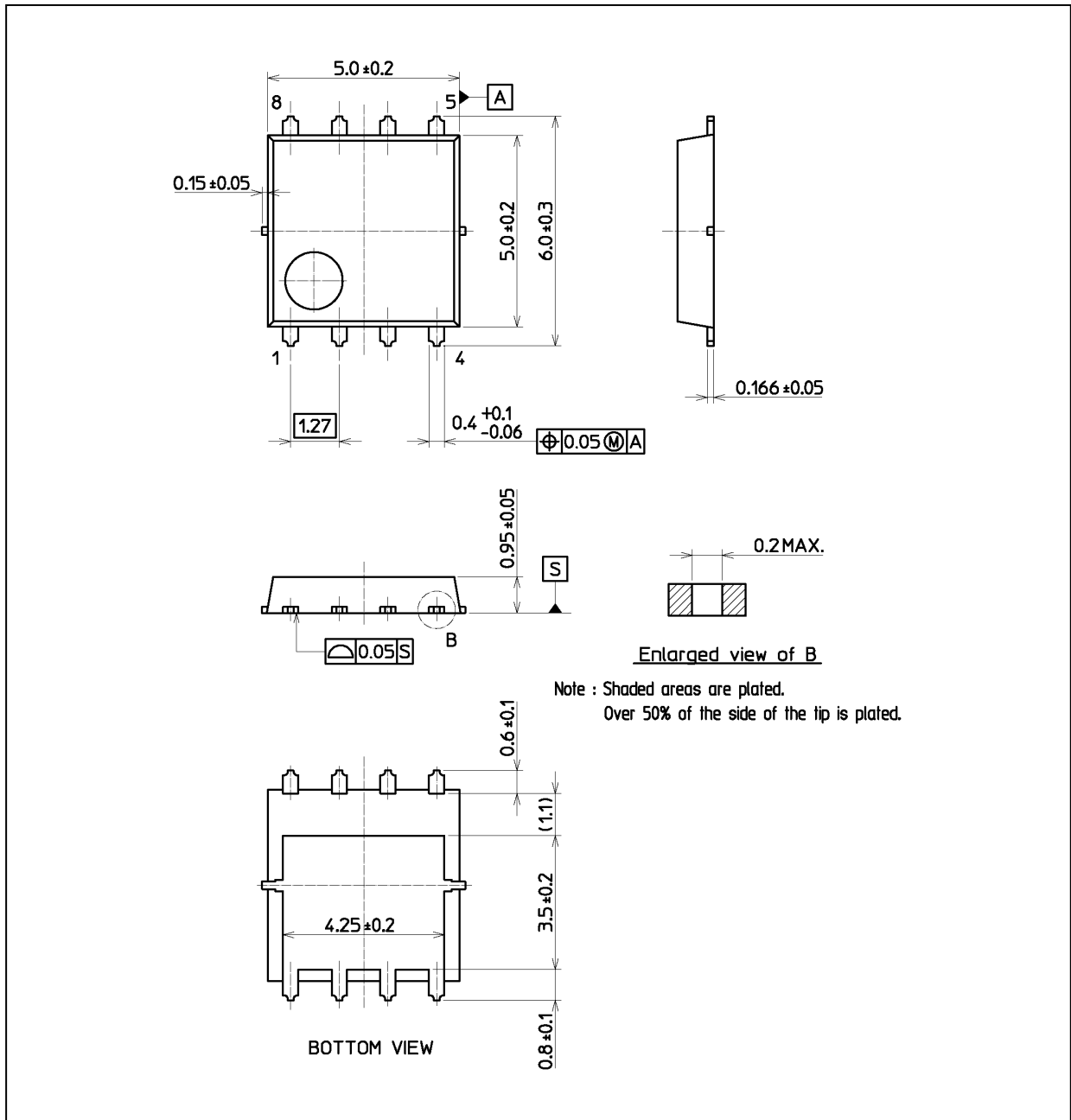
**Fig. 8.20 Safe Operating Area**  
(Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



## Package Dimensions

Unit: mm



Weight: 0.080 g (typ.)

Package Name(s)
TOSHIBA: 2-5Q4A
Nickname: SOP Advance(WF)

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